NSSHNBO

R1518x Series

AEC-Q100 Compliant

1 A 36V Input Low Supply Current LDO for Automotive Applications

NO.EC-329-230124

OUTLINE

R1518x is a CMOS-based LDO that specifically designed for automotive applications featuring 1 A output current and 36 V input voltage. In addition to a conventional regulator circuit, R1518x consists of a constant slope circuit as a soft-start function, a fold-back protection circuit, a short current limit circuit, and a thermal shutdown circuit. Besides the low supply current by CMOS, the operating temperature is -40°C to 125°C and the maximum input voltage is 36 V, the R1518x is very suitable for power source of car accessories.

R1518x is available in R1518xxxxB/D/E/F with the internally fixed output voltage, and R1518xxxxD/F with the auto-discharge function at standby.

The output voltage of R1518x001C can be set with an external resistor, and the setting range is from 2.5V to Max 20V. R1518xxxxB/C/D internally fixes the soft-start time at 120 µs (Typ). R1518Jxx1E/F can adjust the soft-start time with an external capacitor.

R1518x is available in two packages for ultra high wattage: HSOP-6J and TO-252-5-P2.

FEATURES

Input Voltage Range (Maximum Rating) ······	·· 3 5 V to 36 0 V (50 0V)
 Operating Temperature range 	
Supply Current	
Standby Current	··· Τyp. 0.1 μA
Dropout Voltage ······	·· Typ. 0.7 V (Ιουτ = 1 Α, Vουτ = 5.0 V)
Output Voltage Accuracy ······	·· ±0.8% (V _{OUT} ≤ 5.0 V)
Temperature-Drift Coefficient of Output Voltage…	·· Typ. ±60 ppm/°C (−40°C ≤ Ta ≤ 125°C)
Line Regulation	·· Typ. 0.01%/V
Packages ·····	··· HSOP-6J, TO-252-5-P2
Output Voltage Range ······	·· R1518xxxxB/D/E/F: 2.5 V/2.8 V/3.0 V/3.3 V/3.4 V/5.0 V/
	6.0 V/8.0 V/8.5 V/9.0 V
	R1518x001C: Adjustable from 2.5 V to 20.0 V
	with external resistor
	Feedback Voltage: 2.5 V
Built-in Short Current Limit Circuit	·· Typ. 150 mA
Built-in Fold-Back Protection Circuit	··· Min. 1.1 A
Built-in Thermal Shutdown Circuit	·· Typ. 160°C
Built-in Soft-start Circuit ······	·· R1518xxxxB/C/D: Typ.120 μs
	R1518Jxx1E/F: Time adjustable
Ceramic Capacitors can be used	·· R1518xxxxB/D/E/F: 0.1 µF or more
	R1518x001C: 1.0 μF or more

APPLICATIONS

- Power source for car accessories including car audio equipment, car navigation system, and ETC system.
- Power source for control units including EV inverter and charge control.

BLOCK DIAGRAMS



R1518x001C



R1518Jxx1E









SELECTION GUIDE

The output voltage, version, and package type for this device can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free	
R1518Sxx2*-E2-#E		1.000 ====	Vac	Vac	
R1518S001C-E2-#E	HSOP-6J	1,000 pcs	Yes	Yes	
R1518Jxx1*-T1-#E		50 5 D0 0 000 mm			
R1518J001C-T1-#E	TO-252-5-P2	3,000 pcs	Yes	Yes	

xx: Specify the set output voltage (VSET)

2.5 V (25) / 2.8 V (28) / 3.0 V (30) / 3.3 V (33) / 3.4 V (34) / 5.0 V (50) / 6.0 V (60) / 8.0 V (80) / 8.5 V (85) / 9.0 V (90)

Adjustable output voltage setting type is fixed to (00) Note: For R1518S001C-E2-#E and R1518J001C-T1-#E (No auto-discharge function)

- * : Specify the version with desired functions
 - B: No auto-discharge function
 - D: Auto-discharge function
 - E: No auto-discharge function / Adjustable soft-start time setting
 - F: Auto-discharge function / Adjustable soft-start time setting

Note: R1518Sxx2*-E2-#E can provide R1518Sxx2B/D only.

: Specify Automotive Class Code

	Operating Temperature Range	Guaranteed Specs Temperature Range	Screening
А	-40°C to 125°C	25°C	High temperature
K	-40°C to 125°C	-40°C to 125°C	High and low temperature

Auto-discharge function quickly lowers the output voltage to 0 V by releasing the electrical charge in the external capacitor when the chip enable signal is switched from the active mode to the standby mode.

PIN DESCRIPTION



HSOP-6J



HSOP-6J

Pin No.	Symbol		Description			
1	V _{DD}	Input Pin	Input Pin			
2	GND	Ground Pin				
2	GND	Ground Pin	R1518Sxx2B/D			
3	V _{FB}	Feedback Pin	R1518S001C			
4	CE	Chip Enable Pin, Active-h	igh			
5	GND	Ground Pin				
6	Vout	Output Pin				

TO-252-5-P2

Pin No.	Symbol	Description			
1	V _{DD}	Input Pin			
	NC	No Connection	R1518Jxx1B/D		
2	V _{FB}	Feedback Pin	R1518J001C		
	DELAY	Adjustable Soft-start Time Pin	R1518Jxx1E/F		
3	GND	Ground Pin			
4	CE	Chip Enable Pin, Active-high			
5	V _{OUT}	Output Pin			

^{*1} The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). The tab is recommended to connect to the ground plane on the board. Otherwise it may be left floating.

PIN EQUIVALENT CIRCUIT DIAGRAMS



ABSOLUTE MAXMUM RATINGS

Symbol	ltem	Rating	Unit	
VIN	Input Voltage		-0.3 to 50	V
VIN	Peak Input Voltage ^{*1}	60	V	
VCE	Input Voltage (CE Pin)	-0.3 to 50	V	
VFB	Input Voltage (V _{FB} Pin)	-0.3 to 50	V	
Vout	Output Voltage	-0.3 to V _{IN} + 0.3 ≤ 50	V	
Б	Power Dissipation *2	HSOP-6J	3400	mW
PD	(JEDEC STD.51)	4800	IIIVV	
Tj	Junction Temperature	-40 to 150	°C	
Tstg	Storage Temperature Range	−55 to 150	°C	

^{*1} Duration time = 200 ms

*2 Refer to POWER DISSIPATION for detailed information.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	3.5 to 36	V
Та	Operating Temperature Range	-40 to 125	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

 V_{IN} = V_{SET} + 1.0 V, I_{OUT} = 1 mA, C_{IN} = C_{OUT} = 0.1 μ F, unless otherwise noted.

The specifications surrounded by ______ are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 125^{\circ}C$.

R1518xxxxE	B/D (-AE)				-	(Ta	= 25°C)
Symbol	Item	Conditio	ns	Min.	Тур.	Max.	Unit
		Ta = 25°C	$V_{SET} \le 5.0 \text{ V}$	×0.992		×1.008	V
Vout	Output Voltage	14 20 0	V _{SET} > 5.0 V	×0.99		×1.01	V
VOUT	Output Voltage		$V_{SET} \le 5.0 V$	×0.982		×1.018	V
		40 0 3 18 3 120 0	V _{SET} > 5.0 V	×0.98		×1.02	V
ΔV out	Load Regulation	$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 250 m/$	4	-15	3	25	mV
/ΔΙουτ		$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 1 A$		-60	10	60	mV
VDIF	Dropout Voltage	І _{ОUT} = 1 А				roduct-sp naracteris	
lss	Supply Current	I _{OUT} = 0 mA		18	36	μA	
I standby	Standby Current	V _{CE} = 0 V			0.1	2.0	μA
ΔVουτ /ΔVin	Line Regulation	V_{SET} + 0.5 V \leq V _{IN} \leq 3 Under the condition of		0.01	0.02	%/V	
LIM	Output Current Limit	V _{IN} = V _{SET} + 2.0 V	1.1	1.8	2.5	А	
I _{SC}	Short Current Limit	$V_{IN} = 5.0 V, V_{OUT} = 0 V$	V	110	180	250	mA
I ==	CE Pull-down Current	V _{CE} = 5.0 V			0.2	0.6	μA
PD		V _{CE} = 36 V			0.5	1.3	μA
t _{D1}	Soft-start Time 1				120		μs
VCEH	CE Input Voltage "H"			2.2		36	V
VCEL	CE Input Voltage "L"			0		1.0	V
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature		150	160		°C
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature	125	135		°C	
RLOW	Low Output Nch Tr. ON Resistance (R1518xxxxD)	V _{IN} = 14.0 V, V _{CE} = 0	V	1.0	3.2	5.0	kΩ

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj ≈ Ta = 25°C) except for Softstart Time 1.

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 $V_{IN} = V_{FB} (= 2.5 \text{ V}) + 1.0 \text{ V} = 3.5 \text{ V}, I_{OUT} = 1 \text{ mA}, C_{IN} = 0.1 \mu\text{F}, C_{OUT} = 1.0 \mu\text{F}$ unless otherwise noted. The specifications surrounded by are guaranteed by design engineering at -40°C \leq Ta \leq 125°C.

1518x001C	(-AE)	-	1518x001C (-AE) (Ta = 25°C)						
Symbol	ltem	Conditions	Min.	Тур.	Max.	Unit			
V _{FB}		Ta = 25°C	2.480		2.520	V			
V FB	Feedback Voltage	-40°C ≤ Ta ≤ 125°C	2.455		2.545	V			
ΔV_{OUT}	Load Regulation	V _{IN} = 4.5V 1 mA ≤ I _{OUT} ≤ 250 mA	-10	3	10	mV			
/ΔΙουτ		$V_{IN} = 4.5V$ 1 mA $\leq I_{OUT} \leq 1$ A	-25	5	35	mV			
VDIF	Dropout Voltage	Ιουτ = 1 Α		1.0	1.8	V			
lss	Supply Current	Iout = 0 mA		18	36	μA			
Istandby	Standby Current	V _{CE} = 0 V		0.1	2.0	μA			
ΔV_{OUT} / ΔV_{IN}	Line Regulation	$3.5 \text{ V} \le \text{V}_{\text{IN}} \le 36 \text{ V}$		0.01	0.02	%/V			
ILIM	Output Current Limit	V _{IN} = 4.5 V	1.1	1.8	2.5	А			
lsc	Short Current Limit	V _{IN} = 5.0 V, V _{OUT} = V _{FB} = 0 V	110	180	250	mA			
		V _{CE} = 5.0 V		0.2	0.6	μA			
IPD	CE Pull-down Current	V _{CE} = 36 V		0.5	1.3	μA			
t _{D1}	Soft-start Time 1			120		μs			
VCEH	CE Input Voltage "H"		2.2		36	V			
V _{CEL}	CE Input Voltage "L"		0		1.0	V			
TTSD	Thermal Shutdown Temperature	Junction Temperature	150	160		°C			
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature	125	135		°C			

 V_{OUT} = V_{FB} = 2.5 V (excluding short circuit current)

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj \approx Ta = 25°C) except for Softstart Time 1.

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 V_{IN} = V_{SET} + 1.0 V, I_{OUT} = 1 mA, C_{IN} = C_{OUT} = 0.1 $\mu\text{F},$ unless otherwise noted.

The specifications surrounded by ______ are guaranteed by design engineering at -40°C \leq Ta \leq 125°C.

Symbol	Item	Conditio	ns	Min.	Тур.	Max.	Unit
		Ta = 25°C	V _{SET} ≤ 5.0 V	×0.992		×1.008	V
Maxa	Quitaut Valtage	1a - 25 C	V _{SET} > 5.0 V	×0.99		×1.01	V
Vout	Output Voltage	–40°C ≤ Ta ≤ 125°C	$V_{SET} \le 5.0 \text{ V}$	×0.982		×1.018	V
		-40 C S 18 S 123 C	V _{SET} > 5.0 V	×0.98		×1.02	V
ΔVout	Load Regulation	$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 250 mA$	A	-15	3	25	mV
/ΔΙουτ		$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 1 A$		-60	10	60	mV
VDIF	Dropout Voltage	Іоит = 1 А				roduct-sp naracteris	
Iss	Supply Current	I _{OUT} = 0 mA		18	36	μA	
Istandby	Standby Current	V _{CE} = 0 V			0.1	2.0	μA
ΔVout /ΔVin	Line Regulation	V_{SET} + 0.5 V \leq V _{IN} \leq 3 Under the condition of		0.01	0.02	%/V	
ILIM	Output Current Limit	$V_{IN} = V_{SET} + 2.0 V$		1.1	1.8	2.5	А
lsc	Short Current Limit	V _{IN} = 5.0 V, V _{OUT} = 0	V	110	180	250	mA
PD	CE Pull-down Current	V _{CE} = 5.0 V			0.2	0.6	μA
IPD		V _{CE} = 36 V			0.5	1.3	μA
IDELAY	DELAY Current	DELAY = GND		1.5	2.5	3.5	μA
t _{D1}	Soft-start Time 1	DELAY = OPEN			26		μs
t _{D2}	Soft-start Time 2	DELAY = 0.001 μF		210	290	415	μs
V_{CEH}	CE Input Voltage "H"			2.2		36	V
VCEL	CE Input Voltage "L"			0		1.0	V
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature		150	160		°C
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature	125	135		°C	
RLOW	Low Output Nch Tr. ON Resistance (R1518Jxx1F)	V _{IN} = 14.0 V, V _{CE} = 0	V	1.0	3.2	5.0	kΩ

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj \approx Ta = 25°C) except for Softstart Time 1 and Soft-start Time 2.

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The specifications surrounded by _____ are guaranteed by design engineering at -40°C \leq Ta \leq 125°C.

Product Name	Vоит [V] (Ta = 25°С)			V _{ОUT} [V] (−40°С ≤ Ta ≤ 125°С)				
	Min.	Тур.	Max.	Min.	Тур.	Max.	Тур.	Max.
R1518x25xx	2.480	2.500	2.520	2.455	2.500	2.545		
R1518x28xx	2.778	2.800	2.822	2.750	2.800	2.850	1.00	1.80
R1518x30xx	2.976	3.000	3.024	2.946	3.000	3.054		
R1518x33xx	3.274	3.300	3.326	3.241	3.300	3.359	0.90	1.60
R1518x34xx	3.373	3.400	3.427	3.339	3.400	3.461	0.90	1.00
R1518x50xx	4.960	5.000	5.040	4.910	5.000	5.090		
R1518x60xx	5.940	6.000	6.060	5.880	6.000	6.120	0.70	1.30
R1518x80xx	7.920	8.000	8.080	7.840	8.000	8.160		
R1518x85xx	8.415	8.500	8.585	8.330	8.500	8.670	0.65	1.10
R1518x90xx	8.910	9.000	9.090	8.820	9.000	9.180	0.05	1.10

R1518Jxx1B/D/E/F (-AE), R1518Sxx2B/D (-AE) Product-specific Electrical Characteristics (Ta = 25°C)

V _{IN} = V _{SET} + 1.0 \	/, Iоит = 1 mA,	$C_{IN} = C_{OUT} = 0.1$	l μF, unless	otherwise noted.
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Symbol	Item	Conditio	Conditions		Тур.	Max.	Unit
		Ta = 25°C	V _{SET} ≤ 5.0 V	×0.992		×1.008	V
. /		Ta - 25 C	V _{SET} > 5.0 V	×0.99		×1.01	V
Vout	Output Voltage	–40°C ≤ Ta ≤ 125°C	V _{SET} ≤ 5.0 V	×0.982		×1.018	V
		$-40 C \le 1a \le 125 C$	V _{SET} > 5.0 V	×0.98		×1.02	V
ΔVout		$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 250 mA$	4	-15	3	25	mV
/ΔΙουτ	Load Regulation	$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 1 A$		-60	10	60	mV
VDIF	Dropout Voltage	Іоит = 1 А			er to the Product-spec ectrical Characteristic		
Iss	Supply Current	I _{OUT} = 0 mA			18	36	μA
Istandby	Standby Current	V _{CE} = 0 V			0.1	2.0	μA
ΔV_{OUT} / ΔV_{IN}	Line Regulation	V_{SET} + 0.5 V ≤ V _{IN} ≤ 36 V, Under the condition of V _{IN} ≥ 3.5 V			0.01	0.02	%/V
ILIM	Output Current Limit	V _{IN} = V _{SET} + 2.0 V		1.1	1.8	2.5	А
lsc	Short Current Limit	$V_{IN} = 5.0 V, V_{OUT} = 0$	V	110	180	250	mA
PD	CE Pull-down Current	V _{CE} = 5.0 V			0.2	0.6	μA
IPD		V _{CE} = 36 V			0.5	1.3	μA
V_{CEH}	CE Input Voltage "H"			2.2		36	V
VCEL	CE Input Voltage "L"			0		1.0	V
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature		150	160		°C
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature		125	135		°C
RLOW	Low Output Nch Tr. ON Resistance (R1518xxxxD)	$V_{IN} = 14.0 V, V_{CE} = 0$	V	1.0	3.2	5.0	kΩ

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R1518x001C	1518x001C (-KE) (-40 ≤ Ta ≤ 125°					
Symbol	Item	Conditions	Min.	Тур.	Max.	Unit
M		Ta = 25°C	2.480		2.520	V
V _{FB}	Feedback Voltage	-40°C ≤ Ta ≤ 125°C	2.455		2.545	V
ΔVουτ		V _{IN} =4.5 V 1 mA ≤ I _{OUT} ≤ 250 mA	-10	3	10	mV
/Δl _{out}	Load Regulation	V _{IN} = 4.5 V 1 mA ≤ I _{OUT} ≤ 1 A	-25	5	35	mV
VDIF	Dropout Voltage	Ιουт = 1 А		1.0	1.8	V
lss	Supply Current	Iout = 0 mA		18	36	μA
Istandby	Standby Current	V _{CE} = 0 V		0.1	2.0	μA
ΔV _{OUT} /ΔVin	Line Regulation	$3.5 \text{ V} \le \text{V}_{\text{IN}} \le 36 \text{ V}$		0.01	0.02	%/V
ILIM	Output Current Limit	V _{IN} = 4.5 V	1.1	1.8	2.5	А
Isc	Short Current Limit	VIN = 5.0 V, V _{OUT} = V _{FB} = 0 V	110	180	250	mA
_		V _{CE} = 5.0 V		0.2	0.6	μA
IPD	CE Pull-down Current	V _{CE} = 36 V		0.5	1.3	μA
VCEH	CE Input Voltage "H"		2.2		36	V
VCEL	CE Input Voltage "L"		0		1.0	V
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature	150	160		°C
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature	125	135		°C

 $V_{IN} = V_{FB}$ (= 2.5 V) + 1.0 V = 3.5 V, I_{OUT} = 1 mA, C_{IN} = 0.1 μ F, C_{OUT} = 1.0 μ F unless otherwise noted.

V_{OUT} = V_{FB} = 2.5 V (excluding short circuit current)

V_{IN} = V _{SET} +1.0 V, I _{OUT} = 1 mA, C _{IN} = C _{OUT} = 0.1 μ F,	unless otherwise noted.
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Symbol	ltem	Conditio	ns	Min.	Тур.	Max.	Unit
		Ta = 25°C	$V_{\text{SET}} \le 5.0 \text{ V}$	×0.992		×1.008	V
Vout	Quitaut Valtage	Ta - 25 C	V _{SET} > 5.0 V	×0.99		×1.01	V
VOUT	Output Voltage	1000 (T (10500	$V_{\text{SET}} \le 5.0 \text{ V}$	×0.982		×1.018	V
		-40°C ≤ Ta ≤ 125°C	V_{SET} > 5.0 V	×0.98		×1.02	V
ΔVout	Load Regulation	$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 250 mA$	N	-15	3	25	mV
/ΔΙουτ		$V_{IN} = V_{SET} + 2.0 V$ 1 mA $\leq I_{OUT} \leq 1 A$		-60	10	60	mV
VDIF	Dropout Voltage	І _{ОUT} = 1 А				roduct-s haracteri	
lss	Supply Current	Iout = 0 mA			18	36	μA
Istandby	Standby Current	V _{CE} = 0 V			0.1	2.0	μA
ΔV_{OUT} / ΔV_{IN}	Line Regulation	V_{SET} + 0.5 V ≤ V_{IN} ≤ 36 V, Under the condition of V_{IN} ≥ 3.5 V			0.01	0.02	%/V
VIN	Input Voltage			3.5		36	V
ILIM	Output Current Limit	V _{IN} = V _{SET} + 2.0 V		1.1	1.8	2.5	А
lsc	Short Current Limit	VIN = 5.0 V, V _{OUT} = 0 V		110	180	250	mA
		V _{CE} = 5.0 V			0.2	0.6	μA
I _{PD}	CE Pull-down Current	V _{CE} = 36 V			0.5	1.3	μA
IDELAY	DELAY Current	DELAY = GND		1.5	2.5	3.5	μA
VCEH	CE Input Voltage "H"			2.2		36	V
V _{CEL}	CE Input Voltage "L"			0		1.0	V
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature		150	160		°C
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature		125	135		°C
RLOW	Low Output Nch Tr. ON Resistance (R1518Jxx1F)	V _{IN} = 14.0 V, V _{CE} = 0	V	1.0	3.2	5.0	kΩ

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							(−40 ≤ Ta ≤	≦ 125°C)
Product Name	V _{оит} [V] (Та = 25°С)			V _{OUT} [V] (−40°C ≤ Ta ≤ 125°C)			V _{DIF} [V]	
	Min.	Тур.	Max.	Min.	Тур.	Max.	Тур.	Max.
R1518x25xx	2.480	2.500	2.520	2.455	2.500	2.545		
R1518x28xx	2.778	2.800	2.822	2.750	2.800	2.850	1.00	1.80
R1518x30xx	2.976	3.000	3.024	2.946	3.000	3.054		
R1518x33xx	3.274	3.300	3.326	3.241	3.300	3.359	0.90	1.60
R1518x34xx	3.373	3.400	3.427	3.339	3.400	3.461		
R1518x50xx	4.960	5.000	5.040	4.910	5.000	5.090		
R1518x60xx	5.940	6.000	6.060	5.880	6.000	6.120	0.70	1.30
R1518x80xx	7.920	8.000	8.080	7.840	8.000	8.160		
R1518x85xx	8.415	8.500	8.585	8.330	8.500	8.670	0.65	1.10
R1518x90xx	8.910	9.000	9.090	8.820	9.000	9.180	0.65	1.10

R1518Jxx1B/D/E/F (-KE), R1518Sxx2B/D (-KE) Product-specific Electrical Characteristics

TYPICAL APPLICATION



R1518xxxxB/D Typical Application



R1518x001C Typical Application



R1518Jxx1E/F Typical Application

External Components :

Symbol	Description				
R1518xxxxB/D/E/F					
C1	0.1 µF (Ceramic)				
C2	0.1 µF (Ceramic)				
R1518x00	1C				
C1	0.1 μF (Ceramic)				
C2	1.0 μF (Ceramic)				

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TECHNICAL NOTES

Phase Compensation

In LDO regulators, phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use 0.1 μ F or more (R1518xxxxB/D/E/F), 1.0 μ F or more (R1518x001C) of the capacitor C2. When using a tantalum type capacitor and the ESR (Equivalent Series Resistance) value is large, the output might be unstable. Evaluate the circuit including consideration of frequency characteristics.

For the externally adjustable output voltage type (R1518x001C), use 10 k Ω or lower resistance R2.

PCB Layout

Ensure the V_{DD} and GND lines are sufficiently robust. If their impedance is too high, noise pickup or unstable operation may result. Connect 0.1 μ F or more of the capacitor C1 between the V_{DD} and GND, and as close as possible to the pins.

In addition, connect the capacitor C2 between V_{OUT} and GND, and as close as possible to the pins.

TYPICAL APPLICATION FOR IC CHIP BREAKDOWN PREVENTION



When a sudden surge of electrical current travels along the V_{OUT} pin and GND due to a short-circuit, electrical resonance of a circuit involving an output capacitor (C2) and a short circuit inductor generates a negative voltage and may damage the device or the load devices. Connecting a schottky diode (D1) between the V_{OUT} pin and GND has the effect of preventing damage to them.

OPERATION DESCRIPTION

Thermal Shutdown Function

Thermal shutdown function is included in this device. If the junction temperature is more than or equal to 160°C (Typ.), the operation of the regulator would stop. After that, when the junction temperature is less than or equal to 135°C (Typ.), the operation of the regulator would restart. Unless the cause of rising temperature is removed, the regulator repeats on and off, and output waveform would be like consecutive pulses.

Adjustable Output Voltage Setting (R1518x001C)

The output voltage of R1518x001C can be adjusted by using the external divider resistors (R1, R2). By using the following equation, the output voltage (V_{OUT}) can be determined. The voltage which is fixed inside the IC is described as V_{FB} .

 $V_{OUT} = V_{FB} x ((R1 + R2) / R2)$

Recommended Range: 2.5 V \leq V_{OUT} \leq 20.0 V V_{FB} = 2.5 V



Output Voltage Adjustment Using External Divider Resistors (R1, R2)

 R_{IC} of the R1518x001C is approximately Typ. 1.35 M Ω (Ta=25°C, guaranteed by design engineering). For better accuracy, setting R1 << R_{IC} reduces errors. The resistance value for R2 should be set to 10 k Ω or lower. It is easily affected by noises when setting the value of R1 and R2 larger, which makes the impedance of V_{FB} pin larger.

R_{IC} could be affected by the temperature, therefore evaluate the circuit taking the actual conditions of use into account when deciding the resistance values for R1 and R2.

Soft-start Function

R1518x is equipped with a constant slope circuit, which achieves a soft-start function. This circuit allows the output voltage to start up gradually when the CE is turned on. The constant slope circuit minimizes the inrush current at the start-up and also prevents the overshoot of the output voltage. For R1518xxxxB/C/D, the capacitor to create the start-up slope is built in this device that does not require any external components. The start-up time and the start-up slope angle are fixed inside the device. As for R1518Jxx1E/F, the soft-start time is adjustable by inserting the external capacitor to DELAY pin. By using the following equation, the relation between the soft-start time t_D [s] and DELAY pin capacitor C_D [F] is determined.

$$t_D = ((C_D + 90 \times 10^{-12}) / I_{DELAY}) \times 0.73$$

When the capacitor C_D of R1518Jxx1E/F is not used, use the DELAY pin as OPEN. At that time, $C_D = 0$ in the above equation, therefore the start-up time is about 26 µs. However, be sure to consider approximately 50 µs of CE delay time.

The capacity (C_D) of the DELAY pin is discharged when V_{IN} is input and CE = L. If the C_D is restarted without being discharged, the soft start time may be shorter than the set time.





TYPICAL CHARACTERISTICS

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.





R1518x33xx



R1518x50xx







R1518x85xx





R1518x33xx

Nisshinbo Micro Devices Inc.

NO.EC-329-230124





R1518x85xx

9.0













NO.EC-329-230124







Ta (°C)









Nisshinbo Micro Devices Inc.



6) Ripple Rejection vs. Input Voltage (Ta = 25°C, Ripple = 0.2 Vpp)



R1518x33xx (lout = 1 mA)



R1518x25xx, R1518x001C (Iout = 300 mA)



R1518x33xx (lout = 300 mA)







NO.EC-329-230124





R1518x25xx, R1518x001C (C2 = 0.1 µF)







R1518x25xx, R1518x001C (C2 = 10 µF)



R1518x33xx (C2 = 10 μ F)



NO.EC-329-230124



R1518x50xx (C2 = 0.1μ F)







R1518x85xx (C2 = 10 µF)



9) Load Transient Response (Ta = 25°C, $V_{IN} = V_{OUT} + 1.0 V$, tr = tf = 0.5 μ s)

R1518x25xx, R1518x001C (C2 = 0.1 µF)



R1518x25xx, R1518x001C (C2 = 10 µF)









R1518x25xF (C2 = 0.1 μ F, C_D = 1 nF)



R1518x85xB/D (C2 = 0.1 μ F)



R1518J251E/F (C2 = 0.1 μ F, C_D = 1 nF)



R1518J331E/F (C2 = 0.1 μ F, C_D = 1 nF)



R1518x33xF (C2 = 0.1 μ F, C_D = 1 nF)



NO.EC-329-230124



R1518J501E/F (C2 = 0.1 μ F, C_D = 1 nF)



R1518J851E/F (C2 = 0.1 μ F, C_D = 1 nF)



R1518x85xF (C2 = 0.1 μ F, CD = 1 nF)



NO.EC-329-230124



11) Inrush Current Prevention Circuit (Ta = 25°C, I_{OUT} = 1 mA) R1518x25xB/D, R1518x001C

R1518x33xB/D



R1518x50xB/D



R1518x85xB/D



NO.EC-329-230124



4.0



R1518J501E/F (C_D = 10 nF)





Load Transient vs. Output Capacity (C2)

R1518 performs a stable operation by using 0.1 μ F of ceramic capacitor as the output capacitor. However, the variation of output voltage may not meet the demand of the system when input voltage and load current vary. In such cases, the variation of output voltage can be minimized significantly by using 10 μ F or higher ceramic capacitor. When using a high-capacity electrolytic capacitor for the output line, place the electrolytic capacitor a few centimeters apart from the IC after arranging the ceramic capacitor close to the IC.



Load Transient Response

COUT

ESR

 C_{IN} =Ceramic0.1µF, C_{OUT} =Ceramic0.1µF

ESR vs. Output Current

It is recommended that a ceramic type capacitor be used for this device. However, other types of capacitors having lower ESR can also be used. The relation between the output current (I_{OUT}) and the ESR of output capacitor is shown below.



Measurement conditions

Frequency Band: 10 Hz to 2 MHz Measurement Temperature: -40° C to 125°C Hatched area: Noise level is 40 μ V (average) or below Capacitor: C1 = Ceramic 0.1 μ F, C2 = 0.1 μ F





Vin=2.5V to 36V



R1518x001C Test Circuit

 V_{OUT}

 V_{FB}

GND

R1518x001C

 V_{DD}

CE

 C_{IN}

≁

Vin=8.5V to 36V

- 125°C

400

-40°C

500

POWER DISSIPATION

HSOP-6J

PD-HSOP-6J-(125150)-JE-A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

ltem	Measurement Conditions
Environment Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 28 pcs

Measurement Result

(Ta = 25°C, Tjmax = 150°C)

Item	Measurement Result
Power Dissipation	3400 mW
Thermal Resistance (θja)	θja = 37°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 7°C/W

 $\boldsymbol{\theta} ja:$ Junction-to-Ambient Thermal Resistance

wjt: Junction-to-Top Thermal Characterization Parameter



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PACKAGE DIMENSIONS

HSOP-6J

i

DM-HSOP-6J-JE-A



HSOP-6J Package Dimensions

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PART MARKINGS

R1518S

MK-R1518S-JCEC-B

①②③④: Product Code ... <u>Refer to "*R1518S MARK SPECIFICATION TABLE (HSOP-6J)*"</u>
⑤⑥: Lot Number ... Alphanumeric Serial Number



HSOP-6J Part Markings

NOTICE

There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or our distributor before attempting to use AOI.

PART MARKINGS

R1518S

MK-R1518S-JCEC-B

R1518S MARK SPECIFICATION TABLE (HSOP-6J)

R1518Sxx2B

Product Name	0234	V _{SET}
R1518S252B	W 6 2 5	2.5 V
R1518S282B	W 6 2 8	2.8 V
R1518S302B	W 6 3 0	3.0 V
R1518S332B	W 6 3 3	3.3 V
R1518S342B	W 6 3 4	3.4 V
R1518S502B	W 6 5 0	5.0 V
R1518S602B	W 6 6 0	6.0 V
R1518S802B	W 6 8 0	8.0 V
R1518S852B	W 6 8 5	8.5 V
R1518S902B	W 6 9 0	9.0 V

R1518Sxx2D

Product Name	0234	V _{SET}
R1518S252D	W 7 2 5	2.5 V
R1518S282D	W 7 2 8	2.8 V
R1518S302D	W 7 3 0	3.0 V
R1518S332D	W 7 3 3	3.3 V
R1518S342D	W 7 3 4	3.4 V
R1518S502D	W 7 5 0	5.0 V
R1518S602D	W 7 6 0	6.0 V
R1518S802D	W 7 8 0	8.0 V
R1518S852D	W 7 8 5	8.5 V
R1518S902D	W 7 9 0	9.0 V

R1518S001C (Adjustable Output Voltage Setting Type)

Product Name	0234	V _{SET}
R1518S001C	W 2 0 1	-

POWER DISSIPATION

TO-252-5-P2

PD-TO-252-5-P2-(125150)-JE-A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

ltem	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 21 pcs

Measurement Result

(Ta = 25°C, Tjmax = 150°C)

Item	Measurement Result
Power Dissipation	4800 mW
Thermal Resistance (θja)	θja = 26°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 7°C/W

θja: Junction-to-Ambient Thermal Resistance

wjt: Junction-to-Top Thermal Characterization Parameter



Nisshinbo Micro Devices Inc.

PACKAGE DIMENSIONS

TO-252-5-P2

DM-TO-252-5-P2-JE-C



Nisshinbo Micro Devices Inc.

PART MARKINGS

R1518J

MK-R1518J-JCEC-B

12345678: Product Code ... Refer to "R1518J MARK SPECIFICATION TABLE (TO-252-5-P2)" 91: Lot Number ... Alphanumeric Serial Number



TO-252-5-P2 Part Markings

NOTICE

There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or our distributor before attempting to use AOI.

PART MARKINGS

R1518J

MK-R1518J-JCEC-B

R1518J MARK SPECIFICATION TABLE (TO-252-5-P2) Note: ⑧Underbar indicates a blank

R1518Jxx1B

Product Name	02345678	V _{SET}
R1518J251B	L1J251B_	2.5 V
R1518J281B	L1J281B_	2.8 V
R1518J301B	L1J301B_	3.0 V
R1518J331B	L1J331B_	3.3 V
R1518J341B	L1J341B_	3.4 V
R1518J501B	L1J501B_	5.0 V
R1518J601B	L1J601B_	6.0 V
R1518J801B	L1J801B_	8.0 V
R1518J851B	L1J851B_	8.5 V
R1518J901B	L1J901B_	9.0 V

R1518J001C (Adjustable Output Voltage Setting Type)

Product Name	02345678	V_{SET}
R1518J001C	L 2 J 0 0 1 C _	-

R1518Jxx1D

Product Name	02345678	V _{SET}
R1518J251D	L 3 J 2 5 1 D _	2.5 V
R1518J281D	L 3 J 2 8 1 D _	2.8 V
R1518J301D	L 3 J 3 0 1 D _	3.0 V
R1518J331D	L 3 J 3 3 1 D _	3.3 V
R1518J341D	L 3 J 3 4 1 D _	3.4 V
R1518J501D	L3J501D_	5.0 V
R1518J601D	L3J601D_	6.0 V
R1518J801D	L3J801D_	8.0 V
R1518J851D	L 3 J 8 5 1 D _	8.5 V
R1518J901D	L3J901D_	9.0 V

R1518Jxx1E		
Product Name	12345678	V_{SET}
R1518J251E	L 4 J 2 5 1 E _	2.5 V
R1518J281E	L4J281E_	2.8 V
R1518J301E	L4J301E_	3.0 V
R1518J331E	L 4 J 3 3 1 E _	3.3 V
R1518J341E	L 4 J 3 4 1 E _	3.4 V
R1518J501E	L4J501E_	5.0 V
R1518J601E	L4J601E_	6.0 V
R1518J801E	L4J801E_	8.0 V
R1518J851E	L 4 J 8 5 1 E _	8.5 V
R1518J901E	L4J901E_	9.0 V

R1518Jxx1F

Product Name	02345678	V _{SET}
R1518J251F	L 5 J 2 5 1 F _	2.5 V
R1518J281F	L 5 J 2 8 1 F _	2.8 V
R1518J301F	L 5 J 3 0 1 F _	3.0 V
R1518J331F	L 5 J 3 3 1 F _	3.3 V
R1518J341F	L 5 J 3 4 1 F _	3.4 V
R1518J501F	L 5 J 5 0 1 F _	5.0 V
R1518J601F	L 5 J 6 0 1 F _	6.0 V
R1518J801F	L 5 J 8 0 1 F _	8.0 V
R1518J851F	L 5 J 8 5 1 F _	8.5 V
R1518J901F	L5J901F_	9.0 V

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Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.

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